DR-DG-10-MO-RZ 12.5 Gbps RZ Medium Output Voltage Driver Module



Digital Driver



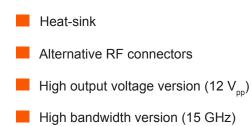
Features

- Output voltage 8 V
- High SNR > 25
- Flat gain up to 7 GHz
- Single voltage power supply

Applications

- LiNbO₃ modulators
- 12.5 Gbps RZ
- OC-192 SONET / SDH
- Research & Development

Options



The DR-DG-10-MO-RZ is a driver module specially designed for 10 Gbps / 12.5 Gbps data transmission with RZ format. It exhibits a 20 dB gain and can deliver an output signal up to 8 V_{nn} .

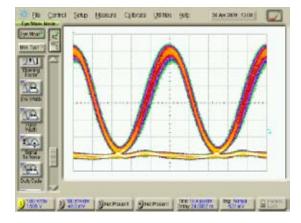
The DR-DG-10-MO-RZ is a key component to obtain high quality 12.5 Gbps eye diagrams with high SNR, low jitter and short rise and fall time. It operates from a single power supply for safety and ease of use, and offers gain control over 3 dB. It comes with SMA type RF connectors (female in, male out) and with an optional heat sink.

Performance Highlights

Parameter	Min	Тур	Max	Unit
Cut-off frequencies	50 k	-	7 G	Hz
Output voltage	-	6	-	V _{pp}
Gain	-	21	-	dB
Saturated output power	21	-	-	dBm
Added jitter	-	1.1	-	ps
Rise / Fall times	-	22 / 22	-	ps

Measurements for V_{bias} = 12 V, V_{amp} = 0.4 V, I_{bias} = 340 mA

10.709 Gbps Output Response



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DC Electrical Characteristics

Parameter	Symbol	Min	Тур	Max	Unit
Supply voltage (fixed)	V_{bias}	-	12	-	V
Current consumption	I _{bias}	-	0.340	-	А
Gain control voltage	V_{amp}	0	0.4	-	V

Electrical Characteristics Conditions: V_{in} = 0.5 V_{pp} , T_{amb} = 25 °C, 50 Ω system

Parameter	Symbol	Condition	Min	Тур	Max	Unit
Lower frequency	f _{3dB} , lower	-3 dB point	-	-	50	kHz
Upper frequency	f _{3dB} , upper	-3 dB point	6	7	-	GHz
Gain	S ₂₁	Small signal	-	21	-	dB
Gain ripple	-	< 7 GHz	-	±1.5	-	dB
Input return loss	S ₁₁	50 kHz < f < 10 GHz	-	-10	-	dB
Output return loss	S ₂₂	50 kHz < f < 10 GHz	-	-10	-	dB
Saturated output power	P _{sat}	$V_{in} = 0.5 V_{pp}$	21	-	22	dBm
Output voltage	V _{out}	$V_{in} = 0.5 V_{pp}$	4	-	8	V _{pp}
Rise / Fall time	t _r / t _f	20 % - 80 %	-	22 / 22	-	ps
Added jitter	J _{RMS}	J _{RMS} = $\sqrt{J^2_{RMS-total} - J^2_{RMS-source}}$	-	1.1	-	ps
Power dissipation	Р	V _{out} = 8 V _{pp}	-	3.2	-	W

Absolute Maximum Ratings

Stresses in excess of the absolute maximum ratings can cause permanent damage to the device. These are absolute stress ratings only. Functional operation of the device is not implied at these or any other conditions in excess of those given in the operational sections of the data sheet. Exposure to absolute maximum ratings for extended periods can adversely affect device reliability.

Parameter	Symbol	Min	Мах	Unit
RF input voltage	V _{in}	-	1.5	V _{pp}
Supply voltage	V_{bias}	0	13	V
DC current	bias	0	0.4	А
Gain control voltage	V _{amp}	0	1	V
Power dissipation	P _{diss}	-	5.2	W
Temperature of operation	T _{op}	-5	+50	W
Storage temperature	T _{st}	-40	+70	°C

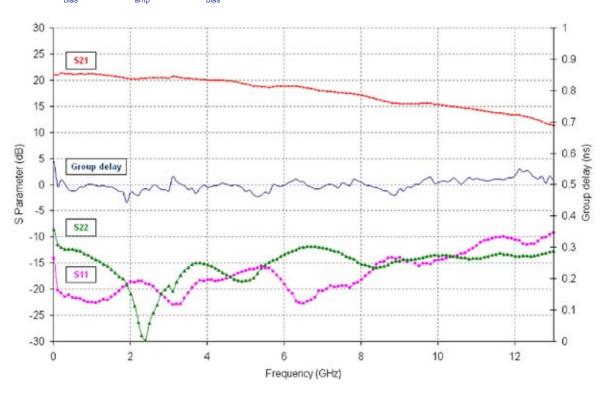
DR-DG-10-MO-RZ 12.5 Gbps RZ Medium Output Voltage

Driver Module

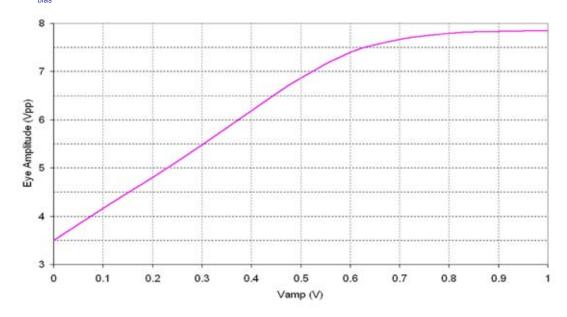


Digital Driver

S Parameters Curves Conditions: V_{bias} = 12 V, V_{amp} = 0.4 V, I_{bias} = 334 mA



Typical Output Voltage Amplitude vs V_{amp} Conditions: V_{bias} = 12 V



DR-DG-10-MO-RZ

12.5 Gbps RZ Medium Output Voltage Driver Module

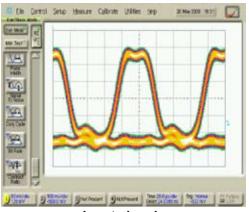


Digital Driver

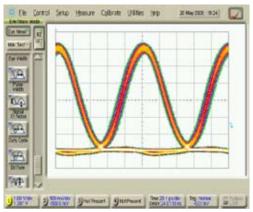
Eye Diagrams

9.952 Gbps data rate

Conditions: Ratio $\frac{1}{2}$, Pattern 2³¹-1 V_{bias} = 12 V, V_{amp} = 0.27 V, I_{bias} = 304 mA



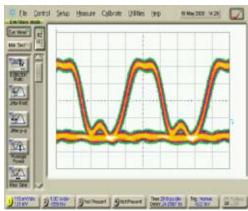
Input signal Genrated by Anritsu MP1758A Eye amplitude = 0.47 V_{pp}, Rise time = 11.6 ps Jitter RMS = 1.05 ps, SNR = 19.8



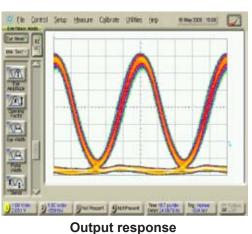
Output response Measured using Agilent 86100B with two 50 GHz 8348A channels module, and without precision time-base module Eye amplitude = 6 V_{pp}, Rise time = 21.4 ps Jitter RMS = 1.34 ps, SNR = 30.6

10.709 Gbps data rate

Conditions: Ratio $\frac{1}{2}$, Pattern 2³¹-1 V_{bias} = 12 V, V_{amp} = 0.4 V, I_{bias} = 334 mA



Input signal Generated with a NEL MOF15A 2:1 selector Eye amplitude = 0.47 V_{pp}, Rise time = 11.6 ps Jitter RMS = 1.08 ps, SNR = 20



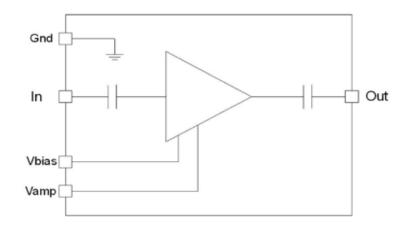
Measured using Agilent 86100B with two 50 GHz 8348A channels module, and without precision time-base module Eye amplitude = $6.4 V_{pp}$, Rise time = 19.9 ps Jitter RMS = 1.27 ps, SNR = 25.3

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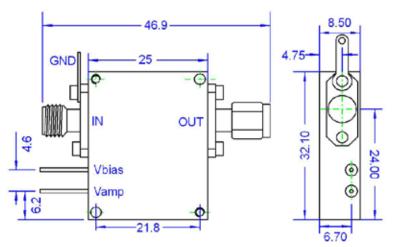
Digital Driver

Electrical Schematic Diagram



Mechanical Diagram and Pinout

All measurements in mm



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The heatsinking of the module is necessary. It's user responsability to use an adequate heatsink. Refer to page 6 for Photline Technologies recommended heatsink.

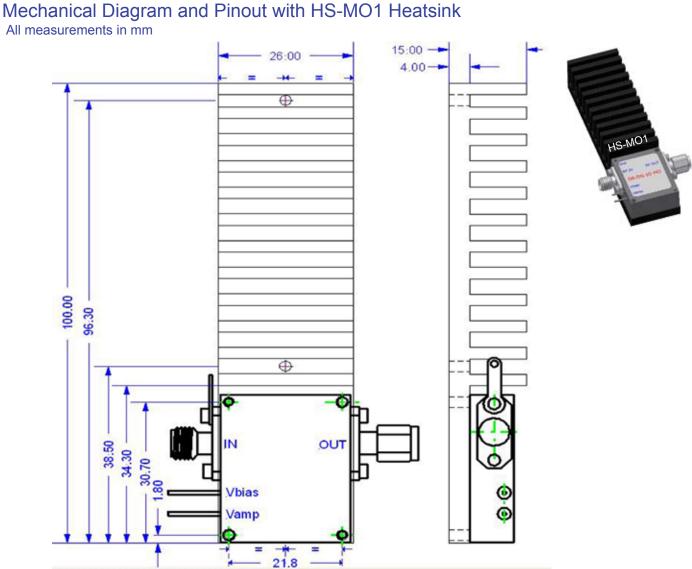
PIN	Function	Operational Notes
IN	RF In	SMA-connector female
OUT	RF Out	SMA-connector male
V _{bias}	Power supply voltage	Set at typical operating specification
V _{amp}	Output voltage amplitude adjustment	Adjust for gain control tuning

DR-DG-10-MO-RZ 12.5 Gbps RZ Medium Output Voltage

Driver Module



Digital Driver



ABOUT US

Photline Technologies is a provider of Fiber Optics Modulation Solutions based on the company LiNb03 modulators and high-speed electronics modules. Photline Technologies offers high speed and high data rate modulation solutions for the telecommunication industry and the defense, aerospace, instruments and sensors markets. The products offered by the company include : comprehensive range of intensity and phase modulators (800 nm, 1060 nm, 1300 nm, 1550 nm), RF drivers and modules, transmitters and modulation units.

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V1, PT-Q1-2009